

74AUP1G132

Low-power 2-input NAND Schmitt trigger

Rev. 5 — 29 June 2012

Product data sheet

1. General description

The 74AUP1G132 provides the single 2-input NAND Schmitt trigger function which accept standard input signals. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H .

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu\text{A}$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from $-40 \text{ }^\circ\text{C}$ to $+85 \text{ }^\circ\text{C}$ and $-40 \text{ }^\circ\text{C}$ to $+125 \text{ }^\circ\text{C}$

3. Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.



4. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|--------------|-------------------|--------|--|----------|
| | Temperature range | Name | Description | |
| 74AUP1G132GW | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 |
| 74AUP1G132GM | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm | SOT886 |
| 74AUP1G132GF | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm | SOT891 |
| 74AUP1G132GN | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm | SOT1115 |
| 74AUP1G132GS | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm | SOT1202 |
| 74AUP1G132GX | -40 °C to +125 °C | X2SON5 | X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm | SOT1226 |

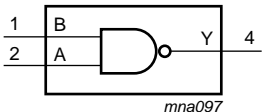

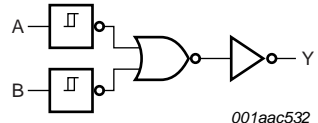
5. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|--------------|-----------------------------|
| 74AUP1G132GW | aE |
| 74AUP1G132GM | aE |
| 74AUP1G132GF | aE |
| 74AUP1G132GN | aE |
| 74AUP1G132GS | aE |
| 74AUP1G132GX | aE |

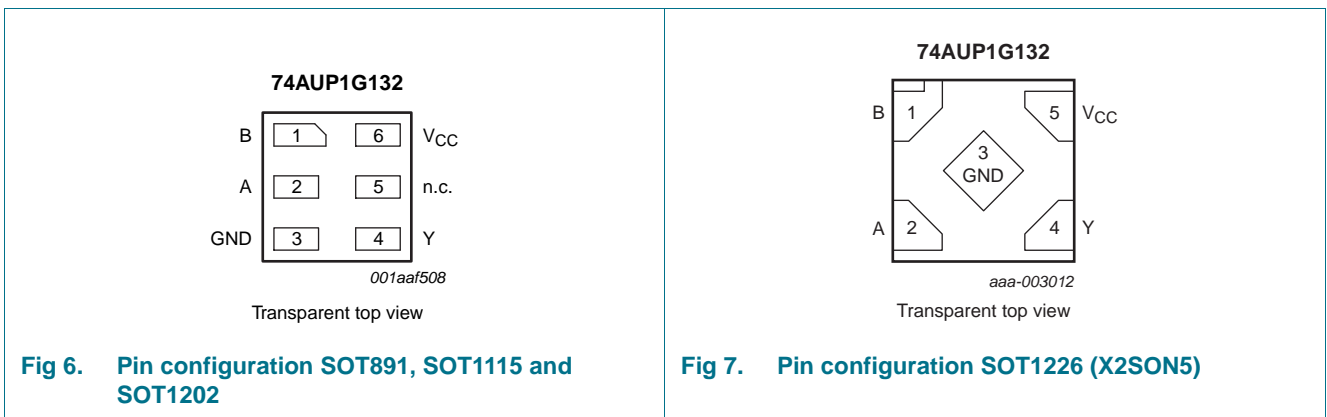
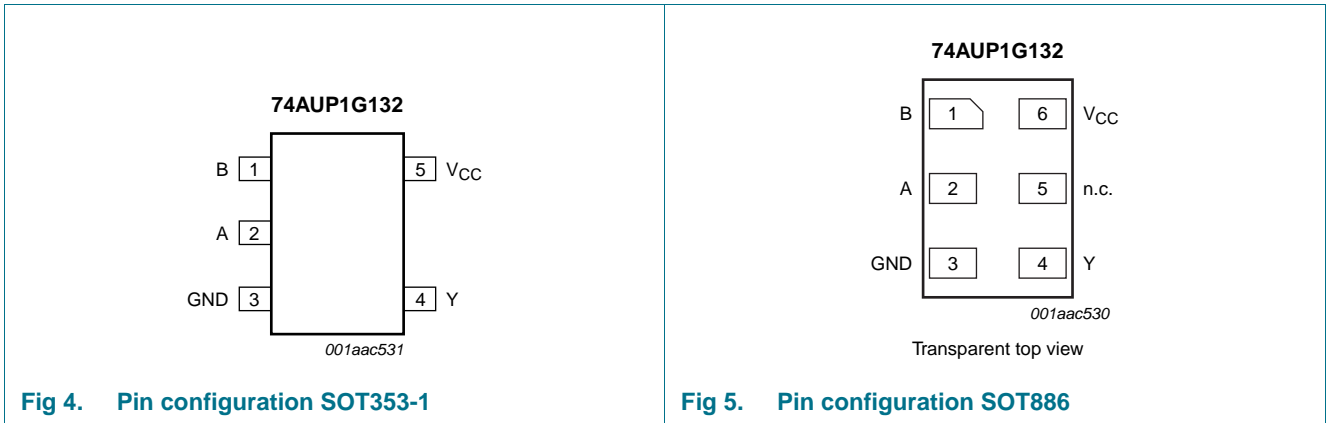
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram

| | | |
|---|---|---|
|  |  |  |
| Fig 1. Logic symbol | Fig 2. IEC logic symbol | Fig 3. Logic diagram |

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

| Symbol | Pin | | Description |
|-----------------|-------------------|-------|----------------|
| | TSSOP5 and X2SON5 | XSON6 | |
| B | 1 | 1 | data input |
| A | 2 | 2 | data input |
| GND | 3 | 3 | ground (0 V) |
| Y | 4 | 4 | data output |
| n.c. | - | 5 | not connected |
| V _{CC} | 5 | 6 | supply voltage |

8. Functional description

Table 4. Function table^[1]

| Input | | Output |
|-------|---|--------|
| A | B | Y |
| L | L | H |
| L | H | H |
| H | L | H |
| H | H | L |

[1] H = HIGH voltage level; L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|---------------------------------|----------|----------|------|
| V_{CC} | supply voltage | | -0.5 | +4.6 | V |
| I_{IK} | input clamping current | $V_I < 0$ V | -50 | - | mA |
| V_I | input voltage | | [1] -0.5 | +4.6 | V |
| I_{OK} | output clamping current | $V_O < 0$ V | -50 | - | mA |
| V_O | output voltage | Active mode and Power-down mode | [1] -0.5 | +4.6 | V |
| I_O | output current | $V_O = 0$ V to V_{CC} | - | ± 20 | mA |
| I_{CC} | supply current | | - | 50 | mA |
| I_{GND} | ground current | | -50 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C | [2] - | 250 | mW |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|---------------------|---------------------------------|-----|----------|------|
| V_{CC} | supply voltage | | 0.8 | 3.6 | V |
| V_I | input voltage | | 0 | 3.6 | V |
| V_O | output voltage | Active mode | 0 | V_{CC} | V |
| | | Power-down mode; $V_{CC} = 0$ V | 0 | 3.6 | V |
| T_{amb} | ambient temperature | | -40 | +125 | °C |

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|--------------------------------------|---|-----------------------|-----|---------------------|---------------|
| $T_{amb} = 25\text{ °C}$ | | | | | | |
| V_{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_O = -20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$ | $V_{CC} - 0.1$ | - | - | V |
| | | $I_O = -1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$ | $0.75 \times V_{CC}$ | - | - | V |
| | | $I_O = -1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$ | 1.11 | - | - | V |
| | | $I_O = -1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$ | 1.32 | - | - | V |
| | | $I_O = -2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$ | 2.05 | - | - | V |
| | | $I_O = -3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$ | 1.9 | - | - | V |
| | | $I_O = -2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$ | 2.72 | - | - | V |
| | | $I_O = -4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$ | 2.6 | - | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$ | - | - | 0.1 | V |
| | | $I_O = 1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$ | - | - | $0.3 \times V_{CC}$ | V |
| | | $I_O = 1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$ | - | - | 0.31 | V |
| | | $I_O = 1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$ | - | - | 0.31 | V |
| | | $I_O = 2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$ | - | - | 0.31 | V |
| | | $I_O = 3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$ | - | - | 0.44 | V |
| | | $I_O = 2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$ | - | - | 0.31 | V |
| | | $I_O = 4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$ | - | - | 0.44 | V |
| I_I | input leakage current | $V_I = \text{GND to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$ | - | - | ± 0.1 | μA |
| I_{OFF} | power-off leakage current | V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V}$ | - | - | ± 0.2 | μA |
| ΔI_{OFF} | additional power-off leakage current | V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }0.2\text{ V}$ | - | - | ± 0.2 | μA |
| I_{CC} | supply current | $V_I = \text{GND or }V_{CC}$; $I_O = 0\text{ A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$ | - | - | 0.5 | μA |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 0.6\text{ V}$; $I_O = 0\text{ A}$; $V_{CC} = 3.3\text{ V}$ | [1] - | - | 40 | μA |
| C_I | input capacitance | $V_I = \text{GND or }V_{CC}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$ | - | 1.1 | - | pF |
| C_O | output capacitance | $V_O = \text{GND}$; $V_{CC} = 0\text{ V}$ | - | 1.7 | - | pF |
| $T_{amb} = -40\text{ °C to }+85\text{ °C}$ | | | | | | |
| V_{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_O = -20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$ | $V_{CC} - 0.1$ | - | - | V |
| | | $I_O = -1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$ | $0.7 \times V_{CC}$ | - | - | V |
| | | $I_O = -1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$ | 1.03 | - | - | V |
| | | $I_O = -1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$ | 1.30 | - | - | V |
| | | $I_O = -2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$ | 1.97 | - | - | V |
| | | $I_O = -3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$ | 1.85 | - | - | V |
| | | $I_O = -2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$ | 2.67 | - | - | V |
| | | $I_O = -4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$ | 2.55 | - | - | V |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|--------------------------------------|--|------------------------|-----|------------------------|------|
| V _{OL} | LOW-level output voltage | V _I = V _{T+} or V _{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.3 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.37 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.33 | V |
| I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.45 | V | | |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.5 | μA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.5 | μA |
| ΔI _{OFF} | additional power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V | - | - | ±0.6 | μA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V | - | - | 0.9 | μA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V | [1] - | - | 50 | μA |
| T_{amb} = -40 °C to +125 °C | | | | | | |
| V _{OH} | HIGH-level output voltage | V _I = V _{T+} or V _{T-} | | | | |
| | | I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | I _O = -1.1 mA; V _{CC} = 1.1 V | 0.6 × V _{CC} | - | - | V |
| | | I _O = -1.7 mA; V _{CC} = 1.4 V | 0.93 | - | - | V |
| | | I _O = -1.9 mA; V _{CC} = 1.65 V | 1.17 | - | - | V |
| | | I _O = -2.3 mA; V _{CC} = 2.3 V | 1.77 | - | - | V |
| | | I _O = -3.1 mA; V _{CC} = 2.3 V | 1.67 | - | - | V |
| | | I _O = -2.7 mA; V _{CC} = 3.0 V | 2.40 | - | - | V |
| I _O = -4.0 mA; V _{CC} = 3.0 V | 2.30 | - | - | V | | |
| V _{OL} | LOW-level output voltage | V _I = V _{T+} or V _{T-} | | | | |
| | | I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V | - | - | 0.11 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | 0.33 × V _{CC} | V |
| | | I _O = 1.7 mA; V _{CC} = 1.4 V | - | - | 0.41 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.39 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.36 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.50 | V |
| | | I _O = 2.7 mA; V _{CC} = 3.0 V | - | - | 0.36 | V |
| I _O = 4.0 mA; V _{CC} = 3.0 V | - | - | 0.50 | V | | |
| I _I | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.75 | μA |
| I _{OFF} | power-off leakage current | V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V | - | - | ±0.75 | μA |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|--------------------------------------|---|-----|-----|------------|---------|
| ΔI_{OFF} | additional power-off leakage current | V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ± 0.75 | μ A |
| I_{CC} | supply current | $V_I = GND$ or V_{CC} ; $I_O = 0$ A; $V_{CC} = 0.8$ V to 3.6 V | - | - | 1.4 | μ A |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 0.6$ V; $I_O = 0$ A; $V_{CC} = 3.3$ V | [1] | - | 75 | μ A |

[1] One input at $V_{CC} - 0.6$ V, other input at V_{CC} or GND.

12. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#)).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +125 °C | | | Unit |
|--------|-----------|------------|-------|--------|-----|-------------------|-------------|--------------|------|
| | | | Min | Typ[1] | Max | Min | Max (85 °C) | Max (125 °C) | |

$C_L = 5$ pF

| | | | | | | | | | |
|----------|-------------------|---|-----|------|------|-----|------|------|----|
| t_{pd} | propagation delay | A or B to Y; see Figure 8 | [2] | | | | | | |
| | | $V_{CC} = 0.8$ V | - | 22.5 | - | - | - | - | ns |
| | | $V_{CC} = 1.1$ V to 1.3 V | 2.6 | 6.3 | 13.4 | 2.4 | 15.1 | 16.6 | ns |
| | | $V_{CC} = 1.4$ V to 1.6 V | 2.2 | 4.6 | 8.2 | 1.9 | 9.7 | 10.7 | ns |
| | | $V_{CC} = 1.65$ V to 1.95 V | 1.9 | 3.9 | 6.6 | 1.7 | 7.9 | 8.7 | ns |
| | | $V_{CC} = 2.3$ V to 2.7 V | 1.7 | 3.2 | 5.3 | 1.5 | 6.2 | 6.8 | ns |
| | | $V_{CC} = 3.0$ V to 3.6 V | 1.6 | 2.9 | 4.7 | 1.4 | 5.6 | 6.2 | ns |

$C_L = 10$ pF

| | | | | | | | | | |
|----------|-------------------|---|-----|------|------|-----|------|------|----|
| t_{pd} | propagation delay | A or B to Y; see Figure 8 | [2] | | | | | | |
| | | $V_{CC} = 0.8$ V | - | 26.1 | - | - | - | - | ns |
| | | $V_{CC} = 1.1$ V to 1.3 V | 3.0 | 7.2 | 15.4 | 2.7 | 17.3 | 19.0 | ns |
| | | $V_{CC} = 1.4$ V to 1.6 V | 2.5 | 5.2 | 9.3 | 2.2 | 11.0 | 12.1 | ns |
| | | $V_{CC} = 1.65$ V to 1.95 V | 2.3 | 4.5 | 7.5 | 2.0 | 9.0 | 9.9 | ns |
| | | $V_{CC} = 2.3$ V to 2.7 V | 2.1 | 3.8 | 6.1 | 1.8 | 7.2 | 7.9 | ns |
| | | $V_{CC} = 3.0$ V to 3.6 V | 2.0 | 3.5 | 5.5 | 1.8 | 6.5 | 7.2 | ns |

$C_L = 15$ pF

| | | | | | | | | | |
|----------|-------------------|---|-----|------|------|-----|------|------|----|
| t_{pd} | propagation delay | A or B to Y; see Figure 8 | [2] | | | | | | |
| | | $V_{CC} = 0.8$ V | - | 29.6 | - | - | - | - | ns |
| | | $V_{CC} = 1.1$ V to 1.3 V | 3.3 | 8.0 | 17.2 | 3.0 | 19.4 | 21.3 | ns |
| | | $V_{CC} = 1.4$ V to 1.6 V | 2.8 | 5.8 | 10.4 | 2.5 | 12.3 | 13.5 | ns |
| | | $V_{CC} = 1.65$ V to 1.95 V | 2.6 | 5.0 | 8.3 | 2.3 | 10.0 | 11.0 | ns |
| | | $V_{CC} = 2.3$ V to 2.7 V | 2.3 | 4.2 | 6.7 | 2.1 | 7.9 | 8.7 | ns |
| | | $V_{CC} = 3.0$ V to 3.6 V | 2.2 | 3.9 | 6.1 | 2.0 | 7.3 | 8.0 | ns |

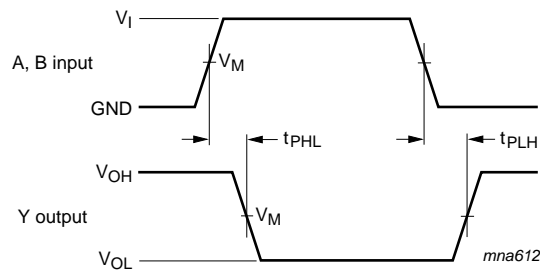
$C_L = 30$ pF

Table 8. Dynamic characteristics ...continued
 Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#)).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +125 °C | | | Unit |
|---|-------------------------------|---|-------|--------------------|------|-------------------|-------------|--------------|------|
| | | | Min | Typ ^[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| t _{pd} | propagation delay | A or B to Y; see Figure 8 ^[2] | | | | | | | |
| | | V _{CC} = 0.8 V | - | 39.9 | - | - | - | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | 4.3 | 10.2 | 22.6 | 3.8 | 25.4 | 27.9 | ns |
| | | V _{CC} = 1.4 V to 1.6 V | 3.6 | 7.3 | 13.3 | 3.2 | 15.8 | 17.4 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | 3.2 | 6.3 | 10.6 | 2.9 | 12.8 | 14.1 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 3.0 | 5.3 | 8.5 | 2.7 | 10.1 | 11.1 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | 2.8 | 5.0 | 7.8 | 2.7 | 9.2 | 10.1 | ns |
| C_L = 5 pF, 10 pF, 15 pF and 30 pF | | | | | | | | | |
| C _{PD} | power dissipation capacitance | f _i = 1 MHz; ^[3] V _I = GND to V _{CC} | | | | | | | |
| | | V _{CC} = 0.8 V | - | 2.6 | - | - | - | - | pF |
| | | V _{CC} = 1.1 V to 1.3 V | - | 2.9 | - | - | - | - | pF |
| | | V _{CC} = 1.4 V to 1.6 V | - | 3.0 | - | - | - | - | pF |
| | | V _{CC} = 1.65 V to 1.95 V | - | 3.2 | - | - | - | - | pF |
| | | V _{CC} = 2.3 V to 2.7 V | - | 3.8 | - | - | - | - | pF |
| | | V _{CC} = 3.0 V to 3.6 V | - | 4.4 | - | - | - | - | pF |

- [1] All typical values are measured at nominal V_{CC}.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL}.
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 C_L = output load capacitance in pF;
 V_{CC} = supply voltage in V;
 N = number of inputs switching;
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

13. Waveforms

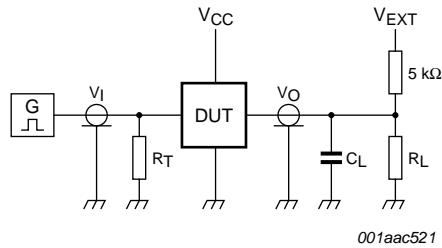


Measurement points are given in [Table 9](#).
 Logic levels: V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig 8. The data input (A or B) to output (Y) propagation delays

Table 9. Measurement points

| Supply voltage | Output | Input | | |
|----------------|---------------------|---------------------|----------|---------------|
| V_{CC} | V_M | V_M | V_I | $t_r = t_f$ |
| 0.8 V to 3.6 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | V_{CC} | ≤ 3.0 ns |



Test data is given in [Table 10](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Load | | V_{EXT} | | |
|----------------|------------------------------|--------------|--------------------|--------------------|--------------------|
| V_{CC} | C_L | R_L [1] | t_{PLH}, t_{PHL} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open | GND | $2 \times V_{CC}$ |

[1] For measuring enable and disable times $R_L = 5$ kΩ, for measuring propagation delays, setup and hold times and pulse width $R_L = 1$ MΩ.

14. Transfer characteristics

Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 9](#)).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +125 °C | | | Unit |
|-----------------|--|---|-------|-----|------|-------------------|-------------|--------------|------|
| | | | Min | Typ | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _{T+} | positive-going threshold voltage | see Figure 10 and Figure 11 | | | | | | | |
| | | V _{CC} = 0.8 V | 0.30 | - | 0.60 | 0.30 | 0.60 | 0.62 | V |
| | | V _{CC} = 1.1 V | 0.53 | - | 0.90 | 0.53 | 0.90 | 0.92 | V |
| | | V _{CC} = 1.4 V | 0.74 | - | 1.11 | 0.74 | 1.11 | 1.13 | V |
| | | V _{CC} = 1.65 V | 0.91 | - | 1.29 | 0.91 | 1.29 | 1.31 | V |
| | | V _{CC} = 2.3 V | 1.37 | - | 1.77 | 1.37 | 1.77 | 1.80 | V |
| | | V _{CC} = 3.0 V | 1.88 | - | 2.29 | 1.88 | 2.29 | 2.32 | V |
| V _{T-} | negative-going threshold voltage | see Figure 10 and Figure 11 | | | | | | | |
| | | V _{CC} = 0.8 V | 0.10 | - | 0.60 | 0.10 | 0.60 | 0.60 | V |
| | | V _{CC} = 1.1 V | 0.26 | - | 0.65 | 0.26 | 0.65 | 0.65 | V |
| | | V _{CC} = 1.4 V | 0.39 | - | 0.75 | 0.39 | 0.75 | 0.75 | V |
| | | V _{CC} = 1.65 V | 0.47 | - | 0.84 | 0.47 | 0.84 | 0.84 | V |
| | | V _{CC} = 2.3 V | 0.69 | - | 1.04 | 0.69 | 1.04 | 1.04 | V |
| | | V _{CC} = 3.0 V | 0.88 | - | 1.24 | 0.88 | 1.24 | 1.24 | V |
| V _H | hysteresis voltage (V _{T+} - V _{T-}); see Figure 10 , Figure 11 , Figure 12 and Figure 13 | V _{CC} = 0.8 V | 0.07 | - | 0.50 | 0.07 | 0.50 | 0.50 | V |
| | | V _{CC} = 1.1 V | 0.08 | - | 0.46 | 0.08 | 0.46 | 0.46 | V |
| | | V _{CC} = 1.4 V | 0.18 | - | 0.56 | 0.18 | 0.56 | 0.56 | V |
| | | V _{CC} = 1.65 V | 0.27 | - | 0.66 | 0.27 | 0.66 | 0.66 | V |
| | | V _{CC} = 2.3 V | 0.53 | - | 0.92 | 0.53 | 0.92 | 0.92 | V |
| | | V _{CC} = 3.0 V | 0.79 | - | 1.31 | 0.79 | 1.31 | 1.31 | V |

15. Waveforms transfer characteristics

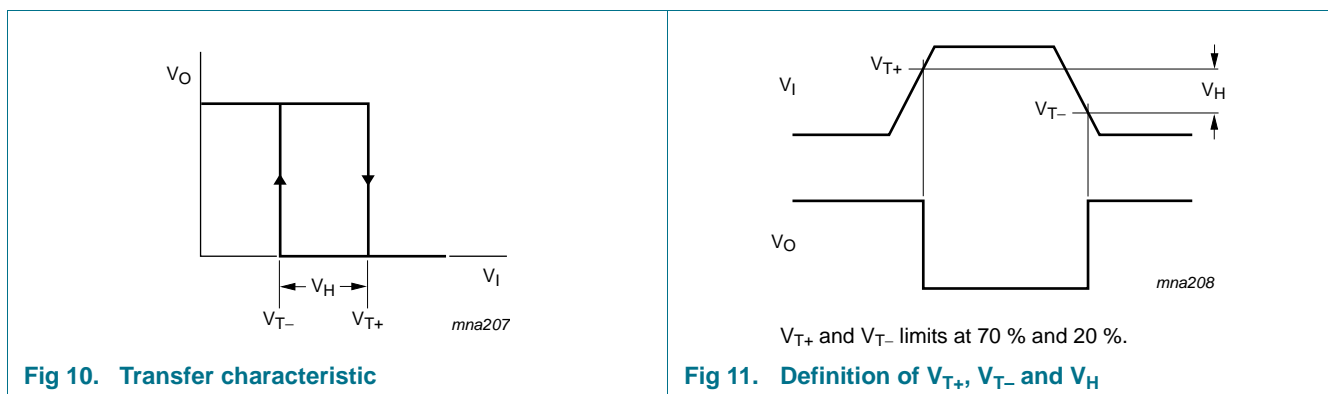


Fig 10. Transfer characteristic

Fig 11. Definition of V_{T+}, V_{T-} and V_H

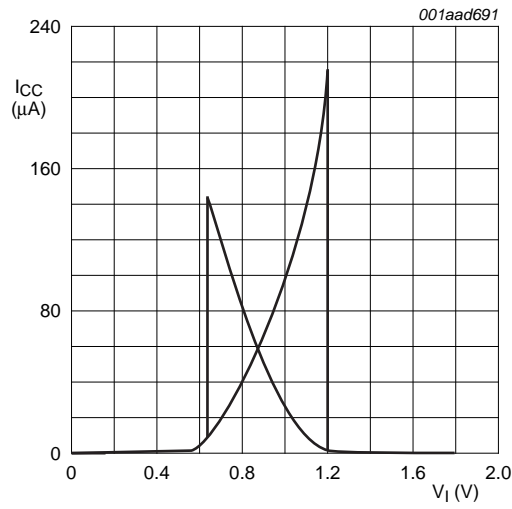


Fig 12. Typical transfer characteristics; $V_{CC} = 1.8$ V

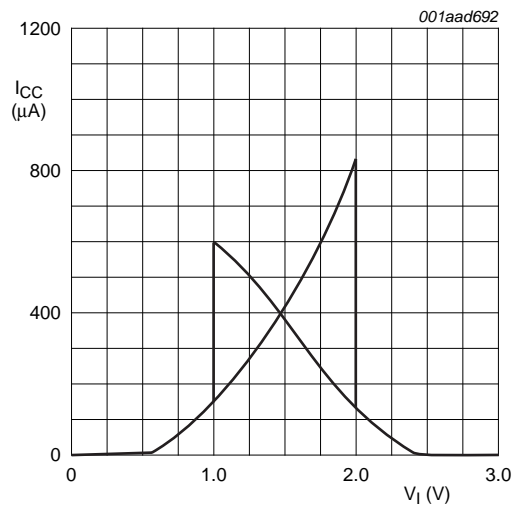


Fig 13. Typical transfer characteristics; $V_{CC} = 3.0$ V

16. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC} \text{ where:}$$

P_{add} = additional power dissipation (μW);

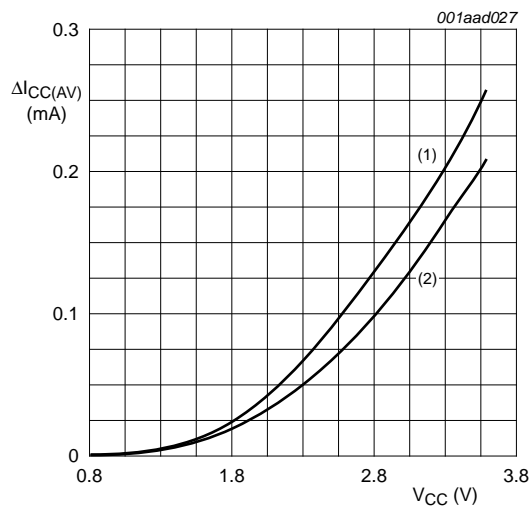
f_i = input frequency (MHz);

t_r = input rise time (ns); 10 % to 90 %;

t_f = input fall time (ns); 90 % to 10 %;

$\Delta I_{CC(AV)}$ = average additional supply current (μA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in [Figure 14](#).



- (1) Positive-going edge.
- (2) Negative-going edge.

Linear change of V_I between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Fig 14. Average I_{CC} as a function of V_{CC}

17. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

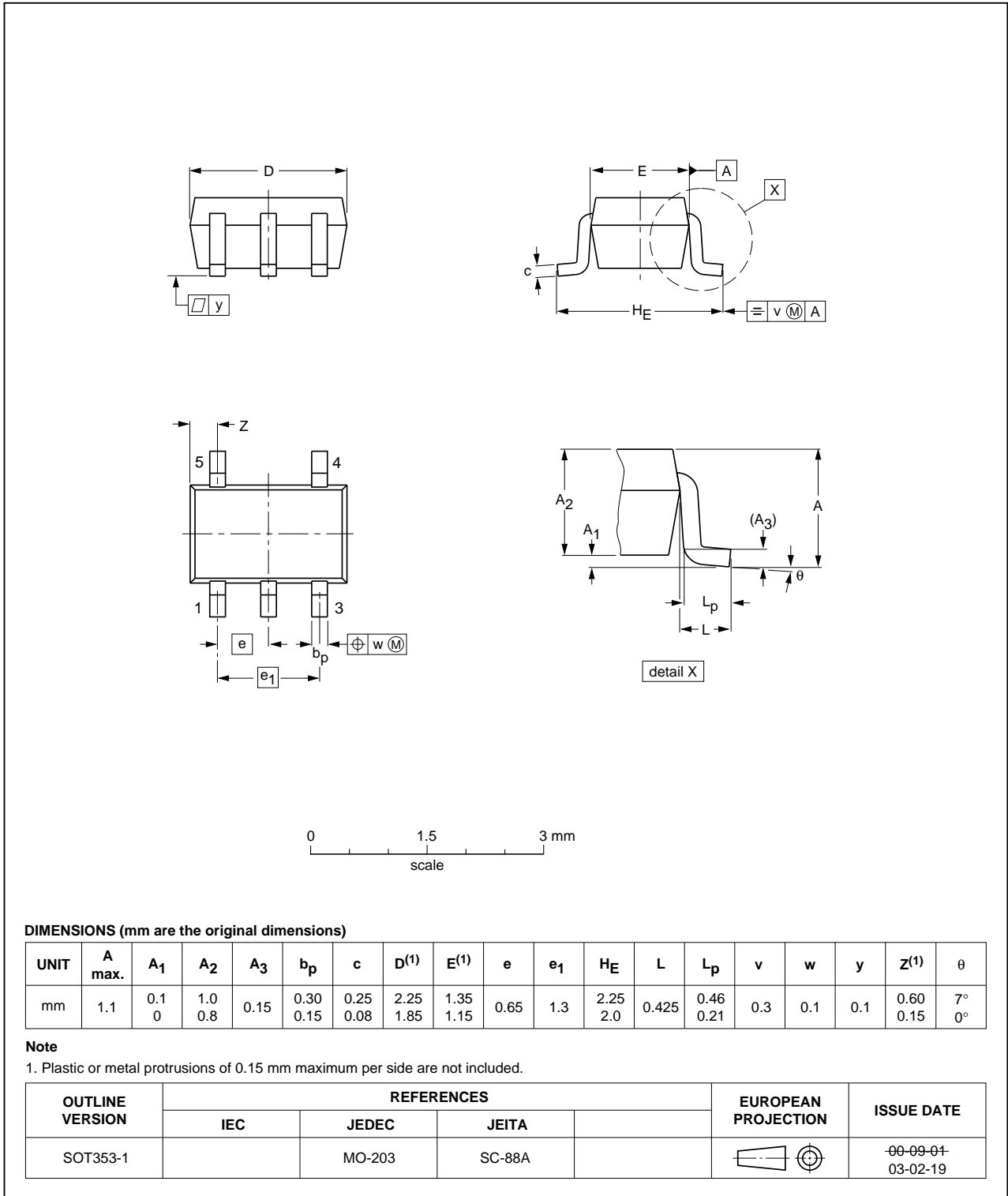


Fig 15. Package outline SOT353-1 (TSSOP5)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886



Fig 16. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

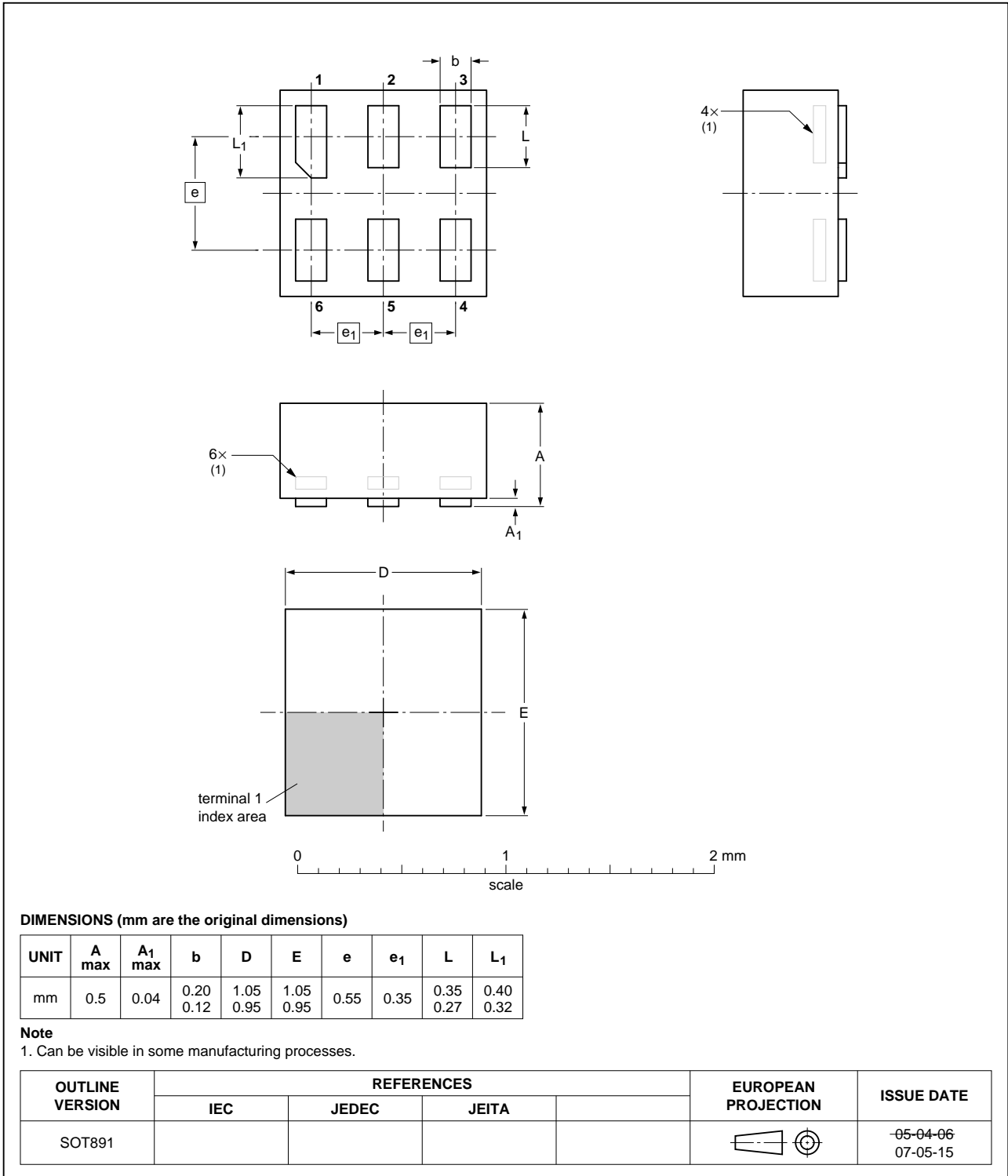


Fig 17. Package outline SOT891 (XSON6)

**XSON6: extremely thin small outline package; no leads;
6 terminals; body 0.9 x 1.0 x 0.35 mm**

SOT1115

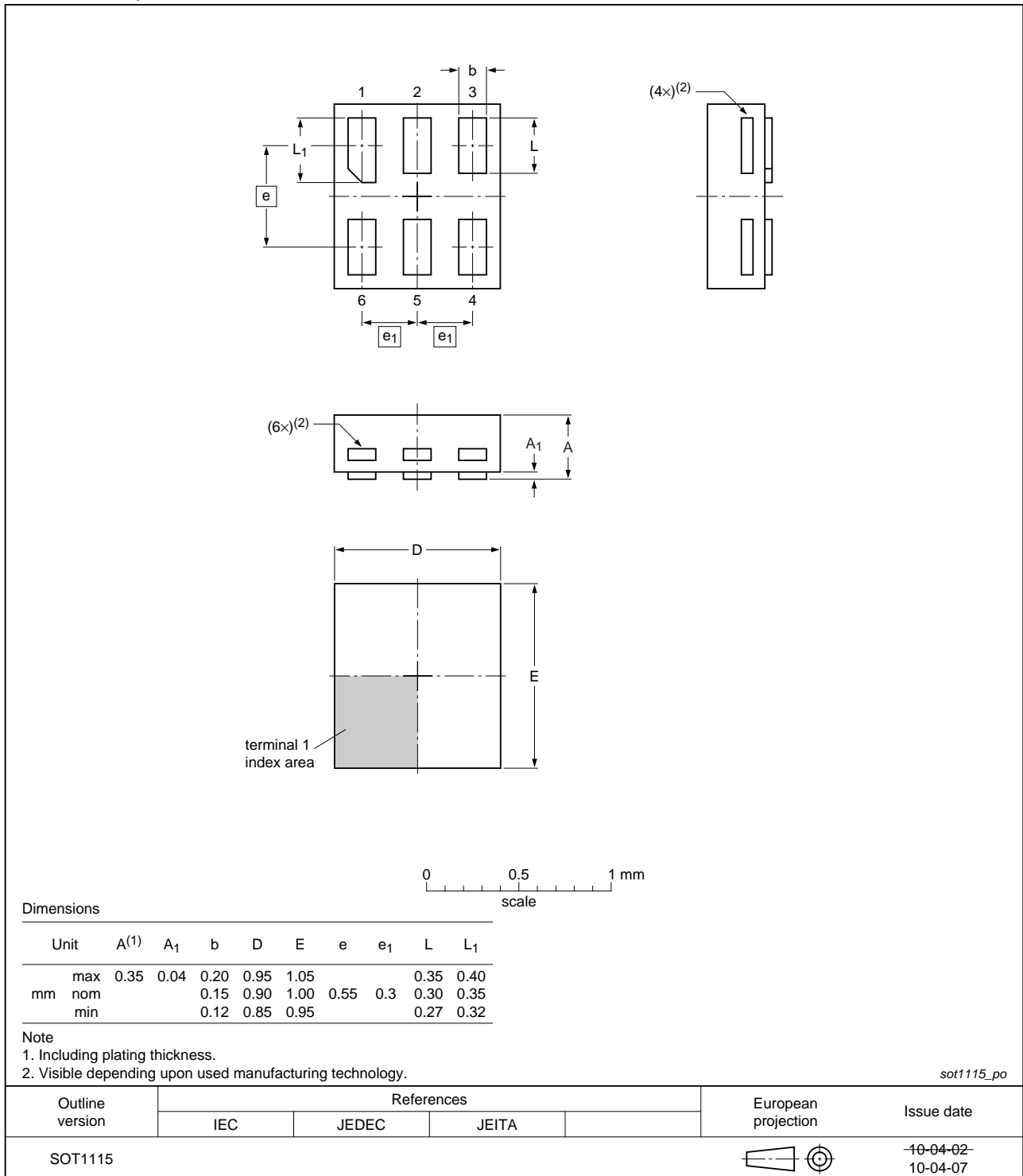


Fig 18. Package outline SOT1115 (XSON6)

**XSON6: extremely thin small outline package; no leads;
6 terminals; body 1.0 x 1.0 x 0.35 mm**

SOT1202

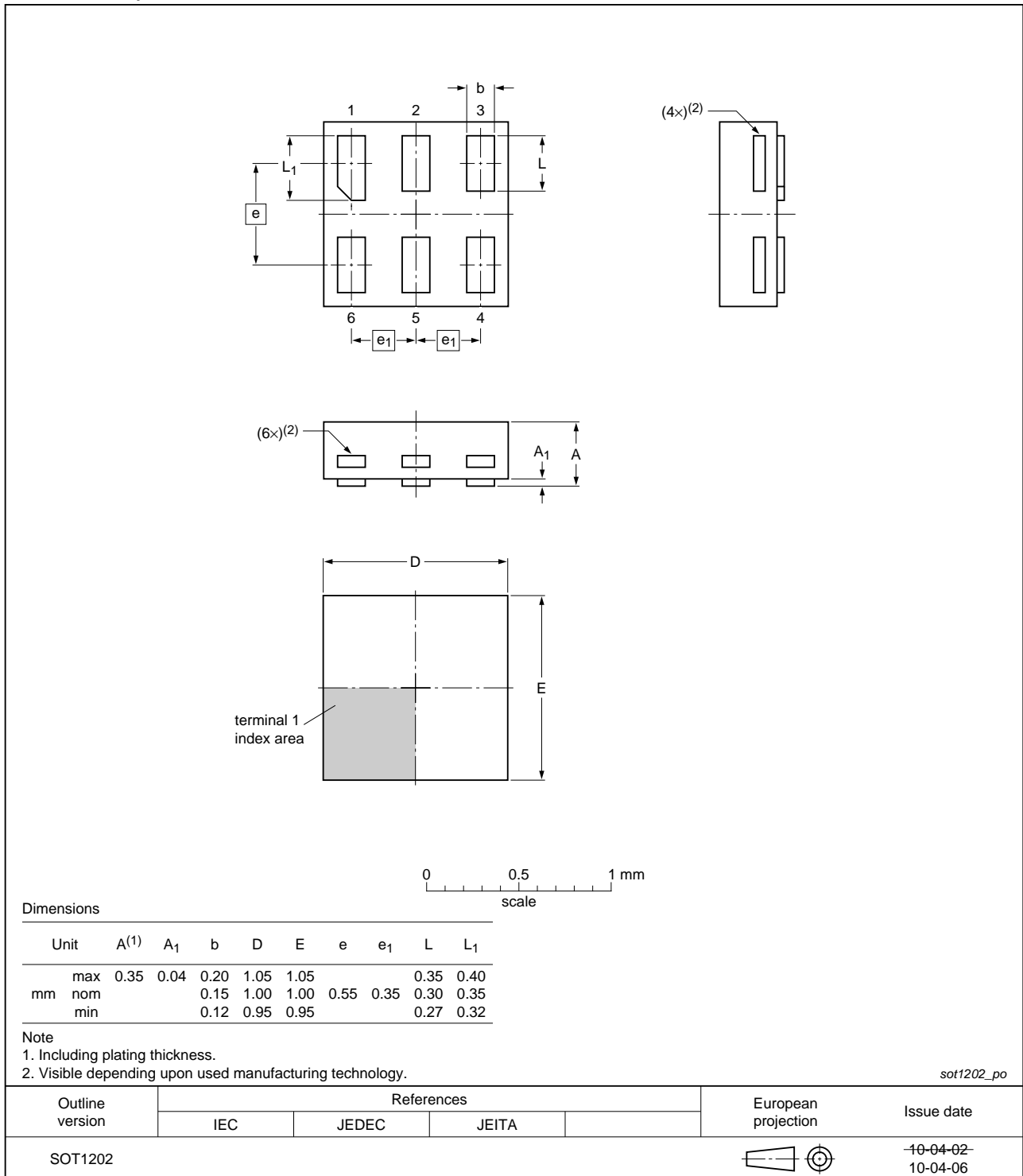


Fig 19. Package outline SOT1202 (XSON6)

X2SON5: plastic thermal enhanced extremely thin small outline package; no leads;
5 terminals; body 0.8 x 0.8 x 0.35 mm

SOT1226

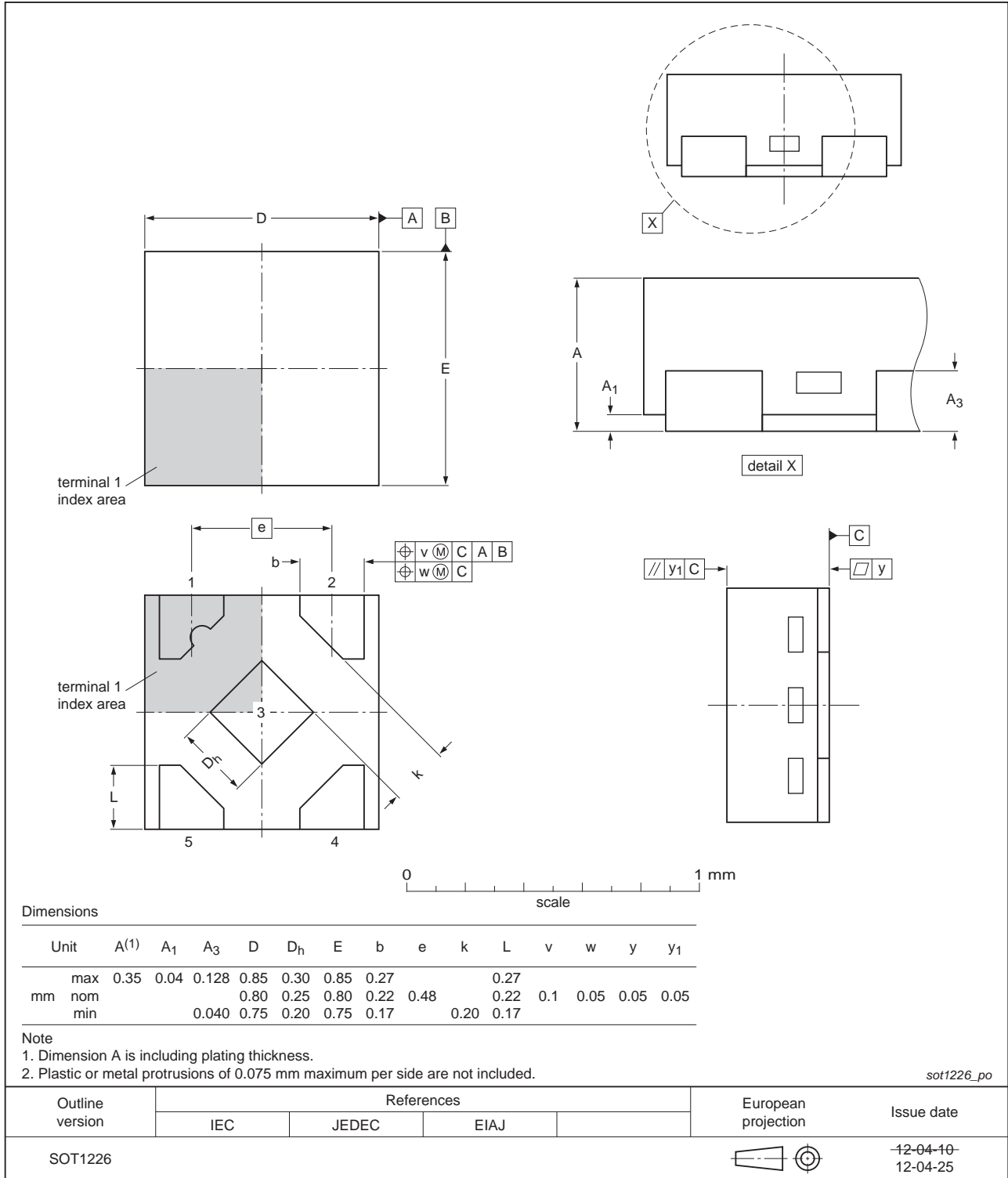


Fig 20. Package outline SOT1226 (X2SON5)

18. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |

19. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|---|--------------------|---------------|----------------|
| 74AUP1G132 v.5 | 20120629 | Product data sheet | - | 74AUP1G132 v.4 |
| Modifications: | <ul style="list-style-type: none"> Added type number 74AUP1G132GX (SOT1226) Package outline drawing of SOT886 (Figure 16) modified. | | | |
| 74AUP1G132 v.4 | 20111124 | Product data sheet | - | 74AUP1G132 v.3 |
| Modifications: | <ul style="list-style-type: none"> Legal pages updated. | | | |
| 74AUP1G132 v.3 | 20101029 | Product data sheet | - | 74AUP1G132 v.2 |
| 74AUP1G132 v.2 | 20090615 | Product data sheet | - | 74AUP1G132 v.1 |
| 74AUP1G132 v.1 | 20061020 | Product data sheet | - | - |

20. Legal information

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| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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